#### **DIODE MODULE**

# MDM300E45A

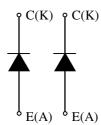
#### TARGET SPEC.

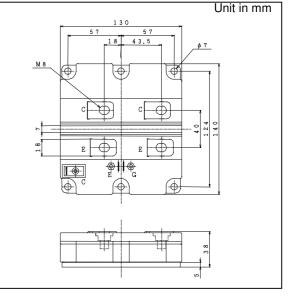
#### **OUTLINE DRAWING**

#### **FEATURES**

- \* Low noise due to soft and fast recovery diodes.
- \* High reliability, high durability diodes.
- \* Isolated heat sink(terminal to base).

#### **CIRCUIT DIAGRAM**





#### ABSOLUTE MAXIMUM RATINGS (TC=25°C)

		,	,		
Item			Symbol	Unit	MDM300E45A
Repetitive Peak Reverse Voltage			V <sub>RRM</sub>	V	4,500
Forward Current		DC	l <sub>F</sub>	А	300
		1ms	I <sub>FM</sub>	~	600
Junction Temperature			Tj	⊃°	-40 $\sim$ +125
Storage Temperature			Tstg	⊃°	-40 $\sim$ +125
Isolation Test	Terminals	Terminals-base		$V_{\text{RMS}}$	6,000 (AC 1 minute)
Voltage	Terminal 1-Terminal 2		V <sub>ISO T-T</sub>		6,000 (AC 1 minute)
Screw Torque	Terminals (M8)		-	N∙m	10 (1)
	Mounting (M6)		-		6 (2)

Notes: (1) Recommended Value 9±1N·m

(2) Recommended Value 5.5±0.5N·m

#### **ELECTRICAL CHARECTERISTICS**

Item	Symbol	Unit	Min.	Тур.	Max.	Test Conditions
Repetitive Reverse Current	I <sub>RRM</sub>	mA	-	7	14	VAK=4,500V, Tj=125°C
Forward Voltage Drop	V <sub>F</sub>	V	3.3	4.5	5.3	IF=300A, Tj=125°C
Reverse Recovery Time	trr	μs	-	0.6		V <sub>CC</sub> =2,600V, Ic=300A, L=130nH
Reverse Recovery Loss	E <sub>rr(10%)</sub>	J/P	-	0.35	0.5	Tj=125°C Rg=6.8Ω(3)

#### PACKAGE CHARECTERISTICS

Symbol	Unit	Min.	Тур.	Max.	Test Conditions
RCE	m $\Omega$	-	0.3	-	
LSCE	nH	-	35	-	
Rth(j-c)	K/W	-	-	0.052	Junction to case
CTI		-	600	-	
Rth(c-f)	K/W	-	0.008	-	Case to fin per module
	RCE LsCE Rth(j-c) CTI	RCE m Ω   LscE nH   Rth(j-c) K/W   CTI	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	RCE     m Ω     -     0.3       LSCE     nH     -     35       Rth(j-c)     K/W     -     -       CTI     -     600	RCE     m Ω     -     0.3     -       LSCE     nH     -     35     -       Rth(j-c)     K/W     -     -     0.052       CTI     -     600     -

Notes:(3) Counter arm; MBN300E45A VGE=+/-15V

 $R_G$  value is the test condition's value for evaluation of the switching times, not recommended value. Please, determine the suitable  $R_G$  value after the measurement of switching waveforms (overshoot voltage, etc.) with appliance mounted.

\* Please contact our representatives at order.

\* For improvement, specifications are subject to change without notice.

\* For actual application, please confirm this spec sheet is the newest revision.

## **HITACHI POWER SEMICONDUCTORS**

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